

C3D04065A

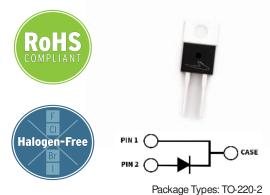
3rd Generation 650 V, 4 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher e iciency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



- Low Forward Voltage (V_F) Drop with Positive Temperature Coe icient
- Zero Reverse Recovery Ourrent / Forward Recovery Voltage
- Temperature-Independent Switching Behavior



ackage Types: TO-220-2 Marking: C3D04065A

Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings ($T_c = 25^{\circ}C$ Unless Otherwise Specified)

| Parameter | Symbol | Value | Unit | Test Conditions | Notes | |
|--|--------------------|-------|------|---|------------|--|
| Repetitive Peak Reverse Voltage | V _{RRM} | 650 | | | | |
| DC Blocking Voltage | V _{DC} | 650 | V | | | |
| | | 13.5 | | T _j = 25 °C | | |
| Continuous Forward Current | I _F | 6 | A | T _j = 135 °C | Fig. 3 | |
| | | 4 | | T _J = 154 °C | | |
| Repetitive Peak Forward Surge Current | I _{FRM} | 17 | | $T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$ | | |
| | | 12 | | $T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$ | | |
| Non-Repetitive Forward Surge Current | I _{FSM} | 30.5 | | $T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ Half Sine Wave}$ | — • | |
| | | 20 | | $T_c = 110 \text{ °C,} t_n = 10 \text{ ms}$, Half Sine Wave | Fig. 8 | |
| Non-Repetitive Peak Forward Surge Current | I _{F,Max} | 220 | | $T_c = 25 \text{ °C}, t_p = 10 \mu\text{s}, \text{ Pulse}$ | | |
| | | 160 | | $T_{c} = 110^{\circ}C, t_{p} = 10 \mu s, Pulse$ | | |
| Power Dissipation | P _{tot} | 52 | W | T _j = 25 °C | Fig. 4 | |
| | | 22.5 | | T ₁ = 110 °C | | |



Electrical Characteristics

| Parameter | Symbol | Тур. | Max. | Unit | Test Conditions | Notes |
|-------------------------|----------------|------|------|------|--|----------|
| Forward Voltage | | 1.4 | 1.7 | V | $I_{\rm F} = 4$ A, $T_{\rm j} = 25$ °C | — Fig. 1 |
| | V _F | 1.7 | 2.4 | | I _F = 4 A, T _j = 175 °C | |
| Reverse Qurrent | | 6 | 30 | μA | $V_{R} = 650 \text{ V}, T_{j} = 25 \text{ °C}$ | |
| | R | 12 | 120 | | V _R = 650 V, T _j = 175 °C | Fig. 2 |
| Total Capacitive Charge | Q _c | 15 | | nC | $V_{\rm R} = 400 \text{ V}, \text{ T}_{\rm j} = 25 \text{ °C}$ | Fig. 5 |
| | | 231 | | | $V_{\rm R} = 0$ V, $T_{\rm j}$ | |
| Total Capacitance | С | | | pF | | |
| | | | | | | |
| | | | | | | |

Typical Performance

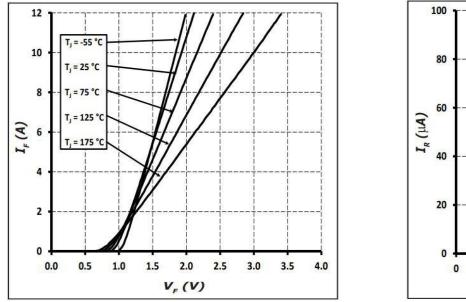


Figure 1 Forward Characteristics

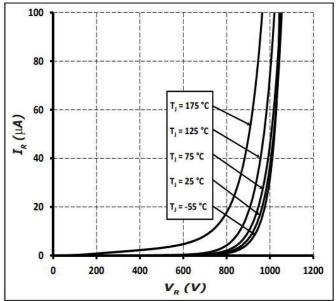


Figure 2 Reverse Characteristics

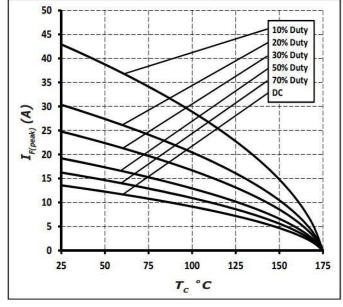


Figure 3 Current Derating

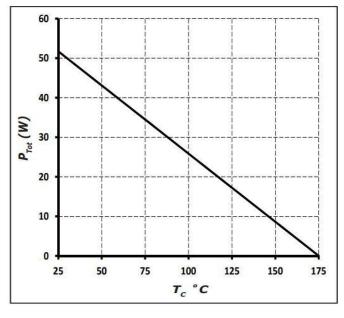


Figure 4 Power Derating

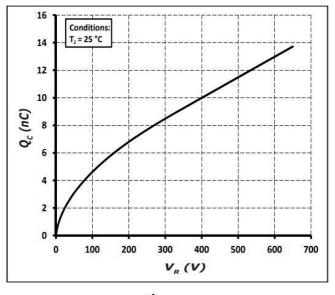


Figure 5 Total Capacitance vs. Reverse Voltage

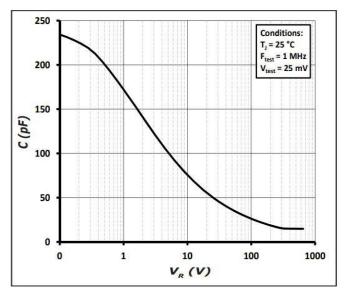


Figure 6 Capacitace vs. Reverse Voltage

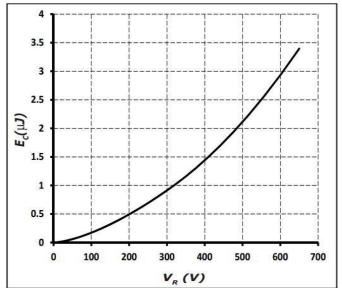


Figure 7 Capacitance Stored Energy

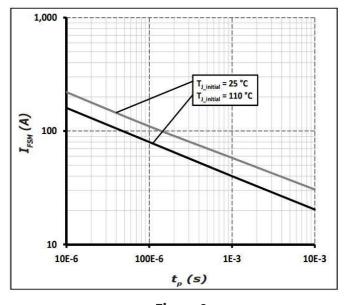
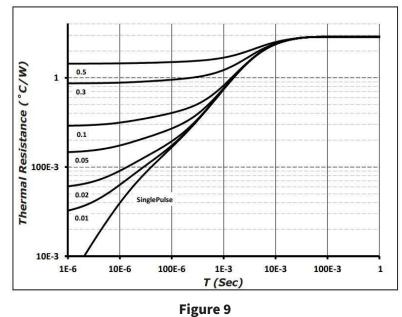
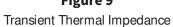
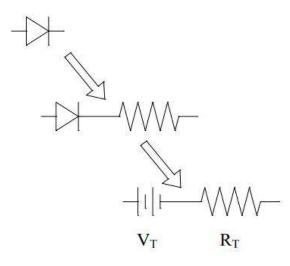


Figure 8 Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)





Diode Model



 $Vf_T = V_T + If * R_T$

$$V_T = 1.00 + (T_J * -1.1*10^{-3})$$

 $R_T = 0.069 + (T_J * 8.3*10^{-4})$

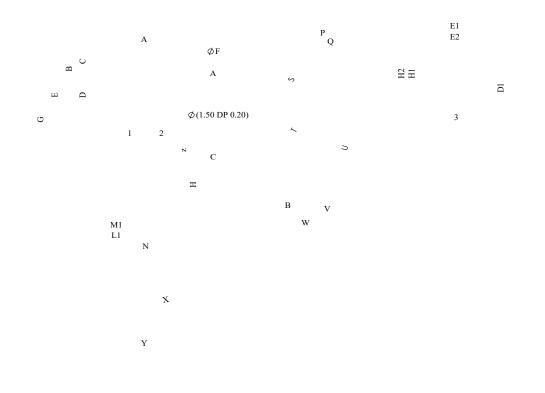
Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C 5





Package Dimensions & Pin-Out

Package: TO-220-2



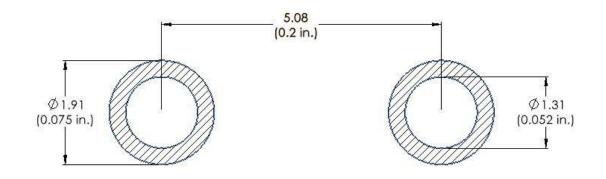
NOTE

- 1. ALL METAL SURFACES ARE TIN PLATED (MATTE), EXCEPT AREA OF CUT.
- 2. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
- 3. ALL DIMENSIONS ARE LISTED IN MILLIMETERS. ANGLES ARE IN DEGREES.
- 4. PACKAGE BURR FLASH SIZE (0.5 mm) IS NOT INCLUDED IN THE DIMENSIONS



Recommended Solder Pad Layout

Primary dimensions shown in mm.



Product Ordering Information

| Order Number | Packing Type |
|--------------|--------------|
| C3D04065A | Tube |

REACh, RoHS, and Halogen-Free compliance documentation available for this product.

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Revision History

| Document Version | Date of Release | Description of Changes |
|------------------|-----------------|--|
| 1 | August-2016 | Initial Release |
| 7 | March-2023 | Update Package Drawing Update Landing Pad |



Notes & Disclaimer

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